

**Erratum: Structural and optical properties of  $\text{MgGa}_2\text{Se}_4$  and  $\text{MgGa}_2\text{Se}_4:\text{Co}^{2+}$  single crystals**  
**[Phys. Rev. B 38, 9469 (1988)]**

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On page 9469, in the Abstract, line 5 from the bottom should read  ${}^4T_2({}^4F)$  not  ${}^4T_1({}^4P)$ .

On page 9469, in the Abstract, lines 3 and 4 from the top should read . . . with lattice constants  $a = 3.950 \text{ \AA}$  and  $c = 38.893 \text{ \AA}$  with a hexagonal transformation for  $\text{MgGa}_2\text{Se}_4$ , and  $a = 4.203 \text{ \AA}$  and  $c = 38.475 \text{ \AA}$  for  $\text{MgGa}_2\text{Se}_4:\text{Co}^{2+}$  single crystals.

On page 9470, in Fig. 1, the bottom part should read  $a = 4.203 \text{ \AA}$ ,  $c = 38.475 \text{ \AA}$  not  $a = 3.950 \text{ \AA}$ ,  $c = 38.893 \text{ \AA}$ .

On page 9470, in the left column, the second paragraph should read: The lattice constants obtained from Fig. 1 are given by  $a = 3.950 \text{ \AA}$  and  $c = 38.893 \text{ \AA}$  for  $\text{MgGa}_2\text{Se}_4$  and  $a = 4.203 \text{ \AA}$  and  $c = 38.475 \text{ \AA}$  for  $\text{MgGa}_2\text{Se}_4:\text{Co}^{2+}$  single crystals. These values are reasonable compared with  $a = 3.88 \text{ \AA}$  and  $c = 38.34 \text{ \AA}$  of the  $\text{MgGa}_2\text{Se}_4$  compound.<sup>1</sup>

On page 9473, in the conclusion of the left column, line 5 should read . . .  $a = 3.950 \text{ \AA}$  and  $c = 38.893 \text{ \AA}$  of hexagonal transformation for  $\text{MgGa}_2\text{Se}_4$ , and  $a = 4.203 \text{ \AA}$  and  $c = 38.475 \text{ \AA}$  for  $\text{MgGa}_2\text{Se}_4:\text{Co}^{2+}$  single crystals.

**Erratum: Selective adsorption in  ${}^4\text{He}$ - $\text{MgO}$  scattering**  
**[Phys. Rev. B 39, 3900 (1989)]**

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The caption to Fig. 2 should read "centered at  $-\mathbf{G}_{mn}$ ." The label in the same figure should be  $\mathbf{G}_{\bar{1}\bar{1}}$  not  $\mathbf{G}_{11}$ .

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**Erratum: Excitonic transitions in strained-layer  $\text{In}_x\text{Ga}_{1-x}\text{As}/\text{InP}$  quantum wells**  
**[Phys. Rev. B 39, 5531 (1989)]**

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As a result of several typographical errors in the preparation of our manuscript Eqs. (5) and (7) are incorrect. Equation (5) should read

$$\Delta \left[ \frac{1}{m_{\text{LH},z}^*(x)} \right] = \frac{1}{4} \left[ \frac{1}{m_{\text{LH},z}^*(x)} - \frac{1}{m_{\text{HH},z}^*(x)} \right] \left[ \frac{1+9X}{(1+2X+9X^2)^{1/2}} - 1 \right]. \quad (5)$$

Equation (7) should read

$$E'(E' - E_g)(E' + \Delta) - K^2 P^2 (E' + \frac{2}{3}\Delta) = 0. \quad (7)$$

These errors do not change the content of the paper as the original calculations were done with the correct equations. We thank S. K. Spitz-Alexander for pointing out these errors.